

## Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

### Features

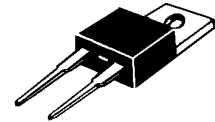
- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 150 Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory
- \* ESD: 4KV(Min.) Human-Body Model



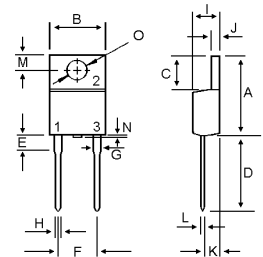
\* In compliance with EU RoHs 2002/95/EC directives

### SCHOTTKY BARRIER RECTIFIERS

**10 AMPERES  
70-100 VOLTS**



**TO-220A**



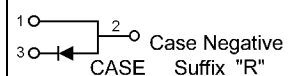
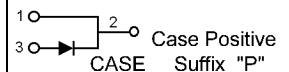
### MAXIMUM RATINGS

Characteristic	Symbol	S10A70	S10A80	S10A90	S10A100	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	70	80	90	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	49	56	63	70	V
Average Rectifier Forward Current	$I_{F(AV)}$	10				A
Peak Repetitive Forward Current (Rate $V_R$ , Square Wave, 20kHz)	$I_{FM}$	10				A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfwave, single phase, 60Hz)	$I_{FSM}$	200				A
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-65 to +150				

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	6.02	6.52
D	13.06	14.62
E	3.57	4.07
F	4.84	5.32
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
N	---	1.00
O	3.70	3.90

### ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	S10A70	S10A80	S10A90	S10A100	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 10$ Amp $T_C = 25$ ) ( $I_F = 10$ Amp $T_C = 125$ )	$V_F$	0.75 0.68		0.85 0.76		V
Typical Thermal Resistance junction to case	$R_{\theta j-c}$	3.4				/w
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25$ ) ( Rated DC Voltage, $T_C = 125$ )	$I_R$		0.2 20			mA



# S10A70 Thru S10A100

FIG-1 FORWARD CURRENT DERATING CURVE

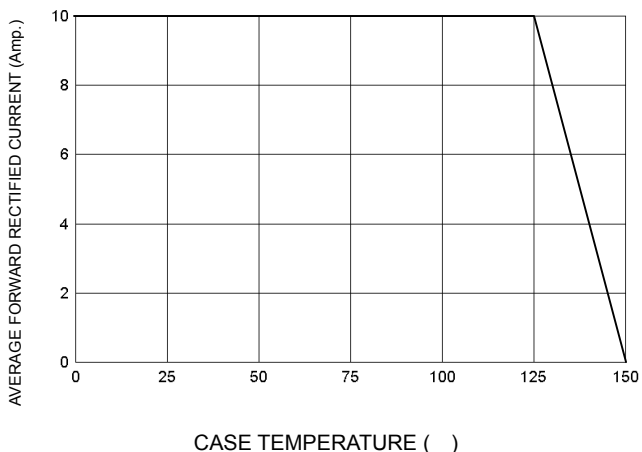


FIG-2 TYPICAL FORWARD CHARACTERISTICS

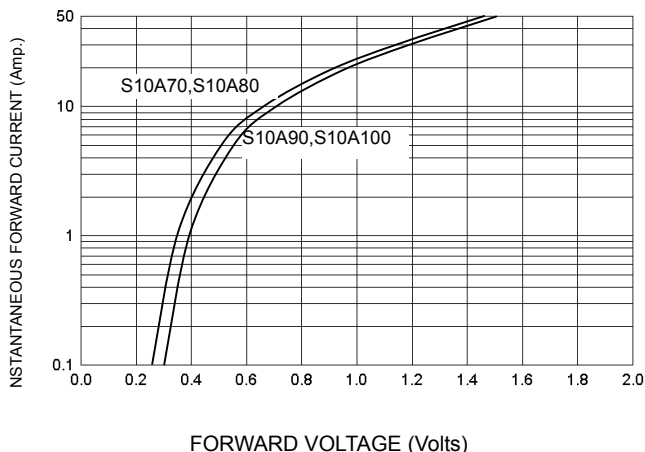


FIG-3 TYPICAL REVERSE CHARACTERISTICS

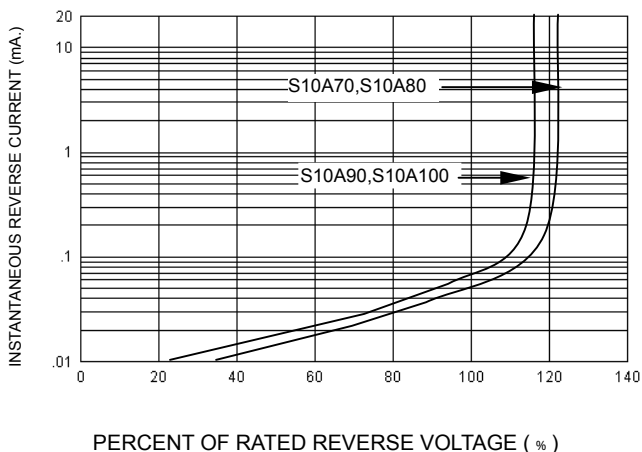


FIG-4 TYPICAL JUNCTION CAPACITANCE

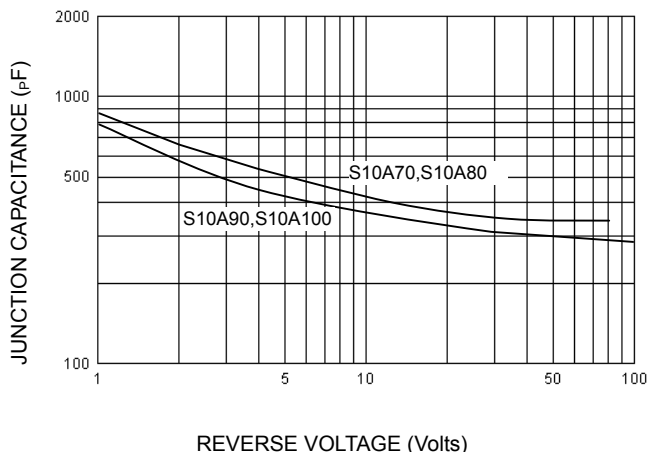
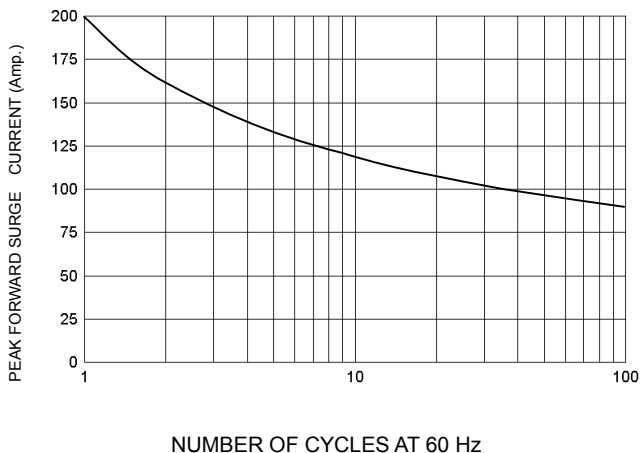


FIG-5 PEAK FORWARD SURGE CURRENT



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